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# High quality factor, ultra-low sintering temperature Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> microwave dielectric ceramics with ultra-low density for antenna substrates

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## Abstract

Dense Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> microwave dielectric ceramics were synthesized at low temperature via solid state reaction using Li<sub>2</sub>CO<sub>3</sub> and LiBO<sub>2</sub>. Optimum permittivity ( $\varepsilon_r$ ) ~ 5.95, quality factor (Qf) ~ 41,800 GHz and temperature coefficient of resonant frequency (TCF) ~ -72 ppm/°C were obtained in ceramics sintered at 640 °C with a ultra-small bulk density ~ 2.003 g/cm<sup>3</sup> (~ 95% relative density, the smallest among all the reported microwave dielectric ceramics). Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> ceramics were shown to be chemically compatible with silver electrodes but reacted with aluminum forming Li<sub>3</sub>AlB<sub>2</sub>O<sub>6</sub> and Li<sub>2</sub>AlBO<sub>4</sub> secondary phases. A prototype patch antenna was fabricated by tape casting and screen printing. The antenna resonated at 4.255 GHz with a bandwidth ~ 279 MHz at -10 dB transmission loss (S<sub>11</sub>) in agreement with simulated results. The Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> microwave dielectric ceramic possesses similar microwave dielectric properties to the commercial materials but much lower density and could be good candidate for both antenna substrate and low temperature co-fired ceramics (LTCC) technology.

KEYWORDS: Microwave Dielectric Ceramic, Low Temperature Co-Fired Ceramic Technology (LTCC), Patch Antenna, Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub>, Dielectric Substrate

## Introduction

Since the 'Internet of Things' (IoT) was first recognized by Ashton in 1999, it has driven a rapid increase in wirelessly connected devices, in areas as diverse as the home, transport, healthcare, military and oil / gas.<sup>1-5</sup> Mobile broadband, driven by the so called 3G/4G into 5G networks has seen in increase in data transmission rates, necessitating improvements in materials in critical components, such as antennas, filters and resonators.<sup>1-6</sup> For a ceramic material to be a dielectric passive substrate for antennas, resonators or filter, three properties need to be optimized: permittivity ( $\varepsilon_r$ ); the temperature coefficient of the resonant frequency (TCF) and dielectric loss or rather its inverse, the quality factor Q, which is often multiplied by the resonant frequency, to give the material constant Qf. The electromagnetic wave length is inversely proportional to the square root of  $\varepsilon_r$  which means dielectric materials with high  $\varepsilon_r$  minimize device dimensions.<sup>6-12</sup> In 2007, Zhou et al.<sup>13</sup> designed a two-element antenna using BiNbO<sub>4</sub> ceramics ( $\varepsilon_r$ =43) as the substrate with an operating frequency about 3.5 GHz and dimensions  $34 \times 34 \times 1$  mm. However, due to the so called 'Chu-limit' the bandwidth was restricted to only 34 MHz at -10 dB, along with poor gain and efficiency.<sup>14</sup> To optimize bandwidth, lower  $\varepsilon_r$  (< 10) substrates are typically utilized in industry with polymeric substrates popular for low cost components and  $Al_2O_3$  for high performance antennas.<sup>15,16</sup> However, despite their importance few commercial antennas optimize the properties of the substrate and tend to view it as a passive component whose primary purpose is to support the metallization.<sup>15-17</sup> Quartz and Al<sub>2</sub>O<sub>3</sub> have exceptional MW properties<sup>18-21</sup> and are ideal as substrates for planar antenna architecture but are expensive because they are fabricated at high temperature (above 1600 °C), polished flat if metallization losses are to be minimized (rough surfaces induce high losses by creating an uneven metal/ceramic interface) and cannot be formed easily into complex shapes. With the development of low temperature co-fired ceramics (LTCC) technology,<sup>8-10</sup> dielectric and inner electrode materials are co-fired together, which decreases the fabrication time and cost, and increases the reliability of highly integrated devices. LTCC technology requires Al<sub>2</sub>O<sub>3</sub> to be sintered below 961 °C (melting point of Ag) which is achieved by the addition of glass based sintering aids but which decrease Qf.<sup>22-24</sup> Recently, novel ultra-low temperature co-fired ceramics (ULTCC) technology has focused on exploring dielectric materials with intrinsic low sintering temperature and a series of novel dielectric materials that can be densified below 550 °C have been explored, such as BaTe<sub>4</sub>O<sub>9</sub>, Li<sub>2</sub>MoO<sub>4</sub> and NaAgMoO<sub>4</sub>.<sup>25-29</sup>

An ideal antenna substrate material for high performance broadband antenna applications should therefore have a low sintering temperature, a small  $\varepsilon_r$  to maximize bandwidth, a high Qf (>30,000), a low TCF and be chemically compatible with Ag. In this contribution, we present the sintering behavior, crystal structure, microwave dielectric properties of Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> ceramic in the Li<sub>2</sub>O–B<sub>2</sub>O<sub>3</sub> binary system fabricated by different processing routes. In addition, a prototype patch antenna using Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> ceramic as a substrate was designed, simulated and then fabricated by tape casting, screen printing and LTCC technology.

## **Experimental Section**

**Sample Synthesis.** Proportionate amounts of reagent-grade starting materials of LiBO<sub>2</sub>, H<sub>3</sub>BO<sub>3</sub>, B<sub>2</sub>O<sub>3</sub> and Li<sub>2</sub>CO<sub>3</sub> (> 99.9%, Sigma-Aldrich) were measured according to the stoichiometric formulation Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub>. Powders were mixed and ball-milled 24 h in isopropanol. The powder mixture was dried and calcined 4h at 580 °C. The

calcined powders were re-milled 24 h and pressed into cylinders (13 mm diameter and  $4 \sim 5$  mm high) at 50 MPa. Samples were sintered 2 h between 600 °C and 650 °C.

**Structural and Microstructural Characterizations.** X-ray diffraction (XRD) was performed using with CuK $\alpha$  radiation (Bruker D2 Phaser) from 5-65° 2 $\theta$  at a step size of 0.02 °. The results were analyzed by the Rietveld profile refinement method, using a FULLPROF program. Thermally etched surfaces were observed using a scanning electron microscopy (SEM, FEI, Inspect F).

**Microwave Dielectric Property and Antenna Measurement.** Dielectric properties at microwave frequency were measured with the  $TE_{01\delta}$  dielectric resonator method<sup>30</sup> using a network analyzer (Advantest R3767CH; Advantest, Tokyo, Japan) and a home-made heating system. The temperature coefficient of resonant frequency TCF ( $\tau_f$ ) was calculated with the following formula:

$$\text{TCF}(\tau_{\rm f}) = \frac{f_{85} - f_{25}}{f_{25} \times (85 - 25)} \times 10^6 \tag{1}$$

where  $f_{85}$  and  $f_{25}$  are the TE<sub>01δ</sub> resonant frequencies at 85 °C and 25 °C, respectively. Transmission parameter S<sub>11</sub> was also measured using the same network analyzer. Design and simulation of the antenna were performed using CST MICROWAVE STUDIO software.

## **Results and Discussions**

The Li<sub>2</sub>O–B<sub>2</sub>O<sub>3</sub> binary diagram has been studied for more than 50 years and shows great complexity (Fig. S1)<sup>31-35</sup> with ~ 10 compounds some of which are high temperature or pressure induced polymorphs.<sup>36</sup> Within industry, solid state reaction is preferred over soft chemical routes for the fabrication of ceramics due to its low cost and ease of scale up. However, the raw material source of B<sub>2</sub>O<sub>3</sub> is problematic for the

fabrication of borate compounds.  $H_3BO_3$  and  $B_2O_3$  were initially utilized for the fabrication of borates but trials quickly illustrated that loss of  $B_2O_3$  due to solubility in aqueous environments and through volatilization was a major issue, leading to the formation of Li<sub>4</sub>B<sub>2</sub>O<sub>5</sub>, Fig. S2. Excess  $H_3BO_3/B_2O_3$  was used to compensate for the loss of  $B_2O_3$  but this resulted in the formation of lithium metaborate (LiBO<sub>2</sub>) as shown in Fig. S2. However, the relative ease with which LiBO<sub>2</sub> forms and its stability in ambient suggests that this compound is an ideal reagent for the formation of Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> through reaction with Li<sub>2</sub>CO<sub>3</sub>, according to the following equation:

$$4\text{LiBO}_2 + \text{Li}_2\text{CO}_3 \xrightarrow{600^{\circ}\text{C}} \text{Li}_6\text{B}_4\text{O}_9 + \text{CO}_2 \uparrow$$
(2)

Fig. 1 shows XRD traces of Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> ceramics sintered using Li<sub>2</sub>CO<sub>3</sub> and LiBO<sub>2</sub> in the appropriate proportions. All peaks were attributed to Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> phase when sintered at 600°C with no secondary phases. Moreover, near full density could be obtained at 630 °C, indicating that LiBO<sub>2</sub> is a superior starting material, with respect to H<sub>3</sub>BO<sub>3</sub> and B<sub>2</sub>O<sub>3</sub>, for the formation of Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub>. Crystal structure refinements were performed on powder samples using Fullprof software and the results are shown in Fig. 1b. The refined cell parameters are a = 3.334(9) Å, b =23.487(0) Å, c = 9.202(9) Å and  $\beta$  = 92.650(2) ° with  $R_p = 5.17$  %,  $R_{wp} = 6.98$  %, and  $R_{exp} = 4.60$  % (the goodness of fit is defined as  $S = R_{wp} / R_{exp} = 1.52$ ), similar to values reported in the literature.<sup>37</sup> The cell volume is 720.06(4)  $Å^3$  and the theoretical density is ~ 2.112 g/cm<sup>3</sup>. There are four formula units per cell and the Li, B and O atoms are distributed on the Wyckoff general position 4e, with full occupancy. A schematic of its crystal structure is inset in Fig. 1b, in which four B atoms are located in the middle of a regular triangle, forming planar BO<sub>3</sub> units, linked by vertices to form quasi-planar B<sub>4</sub>O<sub>9</sub> groups made of four  $BO_3$ . Lithium atoms are coordinated only by oxygen atoms belonging to  $B_4O_9$  groups and located in distorted tetrahedra and in trigonal bipyramids. The refined atomic fractional coordinates from XRD data are listed in Table S1.

To study compatibility with potential electrodes, mixtures of  $Li_6B_4O_9$  and 15 wt.% silver / aluminum powders were co-fired at 630 °C for 2 h. For samples co-fired with silver (Fig. 1), only XRD peaks associated with  $Li_6B_4O_9$  and silver were revealed, from which we conclude that  $Li_6B_4O_9$  ceramics are chemically compatible with silver. However, for samples co-fired with aluminum,  $Li_2AIBO_4$  and  $Li_3AIB_2O_6$  peaks were detected in addition to  $Li_6B_4O_9$  and aluminum. We therefore suggest the following possible reactions:

$$2\text{Li}_{6}\text{B}_{4}\text{O}_{9} + 6\text{Al} \xrightarrow{630^{\circ}\text{C}} 6\text{Li}_{2}\text{AlBO}_{4} + \text{B}_{2}\text{O}_{3}$$
(3)

$$2\text{Li}_{6}\text{B}_{4}\text{O}_{9} + 4\text{Al} + 3\text{O}_{2} \xrightarrow{630^{\circ}\text{C}} 4\text{Li}_{3}\text{AlB}_{2}\text{O}_{6}$$

$$\tag{4}$$

The reaction of  $Li_6B_4O_9$  with aluminum in air to form  $Li_3AlB_2O_6$  occurs with a stoichiometric ratio of Li and B with respect to the starting composition. However, due to inhomogeneity,  $Li_2AlBO_4$  may also react with more aluminum along with amorphous  $B_2O_3$  to form  $Li_3AlB_2O_6$ . Irrespective of the precise reaction, it is evident that  $Li_6B_4O_9$  reacts strongly with aluminum at 630 °C.

An SEM image of a thermally etched surface of  $Li_6B_4O_9$  ceramic is shown in Fig. 2a which reveals a dense microstructure with bar-shape grains (2 ~ 5 µm in length). A BEI image of  $Li_6B_4O_9$  ceramic that reacted for 2 h at 630 °C with 15 wt. % silver is shown in Fig. 2b. Two types of grains with different contrasts are observed. The weight average atomic number of silver is much larger than that of  $Li_6B_4O_9$  and thus these two phases have bright and dark contrast, respectively, as shown in Fig. 2b. There is no evidence of reaction between silver and  $Li_6B_4O_9$ , further confirming their chemical compatibility.

Bulk density of the  $Li_6B_4O_9$  ceramic sintered at 600 °C was 1.873 g/cm<sup>3</sup>, giving a relative density of ~ 88.66 %. When the sintering temperature increased to 640 °C,

optimal density ~ 2.003 g/cm<sup>3</sup> (94.8 % relative density) was obtained and commensurate with an increase in  $\varepsilon_r$  (5.95) and Qf (41,800 GHz) but TCF (- 73 ppm/°C) remained almost constant. Ceramic can be treated as composite containing grains and pores. The permittivity of pore is 1, which is usually much smaller than that of oxide ceramic. Hence, the microwave dielectric permittivity of the Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> ceramic followed the similar change trend to that of relative density and a maximum value ~ 5.95 was reached at 640 °C. Shannon's additive rule<sup>38</sup> may be utilized to establish the theoretical  $\varepsilon_r$  of the matrix phase. The molecular polarizabilities ( $\alpha$ ) in microwave region may be estimated by summing  $\alpha$  of the constituent ions as follows:

$$\alpha(\text{Li}_{6}\text{B}_{4}\text{O}_{9}) = 6\alpha_{\text{L}^{3+}} + 4\alpha_{\text{B}^{3+}} + 9 \times \alpha_{\text{O}^{2-}} = 25.49 \text{ Å}$$
(5)

where  $\alpha_{Li^{3+}}$ ,  $\alpha_{B^{3+}}$  and  $\alpha_{O^{2-}}$  are the respective polarizabilities of  $Li^{3+}$  (1.2 Å<sup>3</sup>), B<sup>3+</sup> (0.05 Å<sup>3</sup>) and O<sup>2+</sup>(2.01 Å<sup>3</sup>) ions.<sup>38</sup> Considering the Clausius–Mosotti relation:<sup>39</sup>

$$\varepsilon = \frac{3V + 8\pi\alpha}{3V - 4\pi\alpha},\tag{6}$$

where V is the cell volume (720.06/4), the calculated permittivity is ~ 5.37, 10 % smaller than the measured value. Microwave dielectric losses include intrinsic and extrinsic parts.<sup>40-42</sup> with the former determined by its crystal structure and representing the upper limit of Qf. The latter is caused by defects and can be minimized by optimal processing.

Al<sub>2</sub>O<sub>3</sub> based substrates are used commercially for the fabrication of radio frequency (RF) devices. Un-doped Al<sub>2</sub>O<sub>3</sub> has a sintering temperature > 1600 °C with a  $\varepsilon_r \sim 10$ , Qf > 600,000 GHz and TCF – 60 ppm/°C.<sup>40,43</sup> To meet the requirement of LTCC, glass frits are added to Al<sub>2</sub>O<sub>3</sub> to lower its sintering temperature below 960 °C accompanied by serious deterioration of Qf. Compared with Al<sub>2</sub>O<sub>3</sub>-based ceramics, Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> has a much lower sintering temperature (~ 630 °C) and small  $\varepsilon_r$  (~ 5.95).

Table I shows a series of ultra-low sintering temperature microwave dielectric ceramics with  $4.2 \le \epsilon_r \le 10.2$ . Among them, Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> exhibits competitive Qf and chemical compatibility with silver electrodes.<sup>44-47</sup> In addition,  $Li_6B_4O_9$  ceramic has the lowest bulk density among all the reported microwave dielectric ceramics and therefore enables light-weighting of devices. The Li<sub>3</sub>AlB<sub>2</sub>O<sub>6</sub> also has a small bulk density (2.385 g/cm<sup>3</sup>) but its relative density is only ~ 88 % in ceramics sintered at 655 °C. Figure S3 and S4 show the dielectric properties of commercial A6 materials<sup>48</sup> from Ferro in comparison with Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> ceramics over a wide frequency range. Although different measurement methods were employed, Fabry-Perot resonant method<sup>49</sup> for A6 and  $TE_{01\delta}$  method for  $Li_6B_4O_9$  ceramic,  $Li_6B_4O_9$  ceramics possess a lower dielectric loss (< 20 GHz) in addition to a lower sintering temperature. The large cell volume (720.06(4)  $Å^3$ ) and small atomic weights of both Li and B determine the small bulk density of Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> ceramic. The low sintering temperature of Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> ceramic is determined by its low melting/decomposition temperature about 700 °C. In the Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> compounds, the B atoms possess sp2 hybrid orbital which prefer to be bonded within plane structures, as the case here along [bc] planes, and this specific crystal structure makes it easy to be moved between [bc] planes at low temperatures,<sup>37</sup> resulting in low densification temperature of ceramic samples. However, the TCF value of Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> ceramic is still too large to be employed in applications. Addition of other microwave dielectric ceramics with positive TCF values might help achieve temperature stable composite ceramics, as the case in Al<sub>2</sub>O<sub>3</sub>-TiO<sub>2</sub> system.<sup>50,51</sup> In combination, its low density (lighter weight per device), small  $\varepsilon_r$ , high Qf, ultra-low sintering temperature and chemical compatibility with Ag make Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> a promising microwave dielectric substrate for 5G applications.

Microwave dielectric ceramics with low permittivity values are suitable for

substrate application due to its small propagation delay, which is proportional to the square root of permittivity. To demonstrate its potential, a patch antenna was designed using CST software with Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> as substrate as shown in Fig. 4a. Silver paste was screen-printed on the surface of a green Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> body and co-fired at 630 °C following with an SMA connect assembled. The optical image of the final prototype is inset in Fig. 4a. A representative SEM cross section of the co-fired sample is also inset in Fig. 4a, from which clear boundary between dielectric and electrode layers can be observed. The simulated and measured S<sub>11</sub> parameters are shown in Fig. 4b. The simulated resonant frequency is 4.262 GHz and the simulated bandwidth is 308 MHz (based on S<sub>11</sub> < -10 dB). The measured result shows that the antenna resonates at 4.255 GHz and has a bandwidth of ~ 279 MHz. The center frequencies of simulated and measured results are therefore, similar but the measured bandwidth is ~ 9 % smaller than that of simulated value.

## Conclusions

Compared with the B<sub>2</sub>O<sub>3</sub> and H<sub>3</sub>BO<sub>3</sub>, LiBO<sub>2</sub> is a more effective starting reagent to synthesize Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> via solid state reaction at 600 °C. Dense ceramics were obtained at 640 °C with a bulk density ~ 2.003 g/cm<sup>3</sup> (relative density ~ 94.8 %) and  $\varepsilon_r$  ~ 5.95, Qf ~ 41,800 GHz and TCF ~ – 72 ppm/°C. A prototype patch antenna was fabricated by exploiting Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> compatibility with silver metallization using LTCC technology. Good agreement of measured and simulated values of transmission parameter S<sub>11</sub> were obtained with a resonant frequency ~ 4.255 GHz and a bandwidth ~ 279 MHz.

# **ASSOCIATED CONTENT**

### **Supporting Information**

We added the phase diagram of Li<sub>2</sub>O-B<sub>2</sub>O<sub>3</sub>, XRD patterns of Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> powders using H<sub>3</sub>BO<sub>3</sub>/B<sub>2</sub>O<sub>3</sub> as initial materials, and dielectric properties of the Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> ceramics as a function of frequency (9.5~ 14.7 GHz) in supporting information. The Supporting Information is available free of charge on the ACS Publications

website at DOI:

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#### Notes

The authors declare no competing financial interest.

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# **Table Captions**

Table I. Sintering temperatures and microwave dielectric properties of some low permittivity LTCC materials in order of bulk density in order of density.

$(g/cm^3)$						Ref.
				Value		
				(ppm/ºC)		
2.003	640	6.0	41,800	-72	<b>♀Ag; ♂Al</b>	This work
2.385	650	4.2	12,460	-290	not studied	44
3.031	540	5.5	46,000	-160	<b>♀Ag &amp; Al</b>	28
3.211	675	9.1	33,730	-160	∂Ag	45
3.891	570	9.5	50,000	-73	<b>♀Ag &amp; Al</b>	46
4.567	640	5.5	62,000	-146	<b>♀Ag &amp; Al</b>	26
4.928	400	7.9	33,000	-120	♀Ag & Al	29
6.183	700	10.2	10,750	-41	not studied	47
	<ol> <li>2.385</li> <li>3.031</li> <li>3.211</li> <li>3.891</li> <li>4.567</li> <li>4.928</li> </ol>	<ul> <li>2.385</li> <li>3.031</li> <li>540</li> <li>3.211</li> <li>675</li> <li>3.891</li> <li>570</li> <li>4.567</li> <li>640</li> <li>4.928</li> <li>400</li> </ul>	2.3856504.23.0315405.53.2116759.13.8915709.54.5676405.54.9284007.9	2.3856504.212,4603.0315405.546,0003.2116759.133,7303.8915709.550,0004.5676405.562,0004.9284007.933,000	2.003 $640$ $6.0$ $41,800$ $-72$ $2.385$ $650$ $4.2$ $12,460$ $-290$ $3.031$ $540$ $5.5$ $46,000$ $-160$ $3.211$ $675$ $9.1$ $33,730$ $-160$ $3.891$ $570$ $9.5$ $50,000$ $-73$ $4.567$ $640$ $5.5$ $62,000$ $-146$ $4.928$ $400$ $7.9$ $33,000$ $-120$	2.003       640       6.0       41,800       -72       ♀Ag; ♂AI         2.385       650       4.2       12,460       -290       not studied         3.031       540       5.5       46,000       -160       ♀Ag & Al         3.211       675       9.1       33,730       -160       ♂Ag         3.891       570       9.5       50,000       -73       ♀Ag & Al         4.567       640       5.5       62,000       -146       ♀Ag & Al         4.928       400       7.9       33,000       -120       ♀Ag & Al

S.T.= Sintering Temperature;  $\mathcal{Q}$ =chemically compatible;  $\mathcal{J}$ =not chemically

compatible; \* Relative density =88 %

# **Figure Captions**

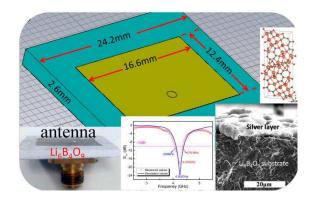
Fig. 1 a) XRD patterns of the  $Li_6B_4O_9$  ceramic sintered at 600 °C, co-fired ceramics with 15 wt. % aluminum and silver, respectively, at 630 °C for 2 h, and b) crystal structure and Rietveld refinement of  $Li_6B_4O_9$ .

Fig. 2 a) SEM image of thermally etched surface of Li<sub>6</sub>B<sub>4</sub>O<sub>9</sub> ceramic sintered at 630 °C and b) BEI image of the co-fired ceramic with 15 wt. % at 630 °C.

Fig. 3 a) Relative density and b) microwave dielectric properties of the  $Li_6B_4O_9$  ceramics as a function sintering temperature (resonant frequencies 10.4 ~ 10.9 GHz).

Fig. 4 a) Schematic, optical and SEM images of the antenna using  $Li_6B_4O_9$  and silver as substrate and patterns, respectively, and b) the measured and simulated values of transmission parameter  $S_{11}$ .

# **TOC/Abstract Graphic**



# Synopsis:

 $Li_6B_4O_9$  microwave dielectric ceramic can be well densified at 640 °C and a prototype patch antenna showed good transmission properties.

